

#### 20V P-Channel Enhancement Mode MOSFET

Voltage

-20 V

Current

-1000mA

#### **Features**

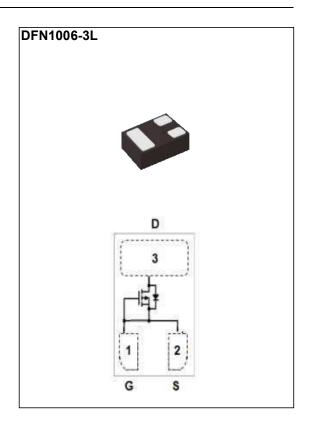
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- Green molding compound

#### **Mechanical Data**

• Case: DFN1006-3L Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.00002 ounces, 0.0007 grams



## **Maximum Ratings and Thermal Characteristics** (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNITS		
Drain-Source Voltage	V <sub>DS</sub>	-20	V		
Gate-Source Voltage		V <sub>GS</sub>			<u>+</u> 12
Continuous Drain Current (Note 4)		I <sub>D</sub>	-1000	mA	
Pulsed Drain Current (Note 1)		I <sub>DM</sub>	-1500		
Power Dissipation	T <sub>a</sub> =25°C	_	500	mW	
	Derate above 25°C	P <sub>D</sub>	4	mW/ °C	
Operating Junction and Storage Temperature Range		T <sub>J</sub> ,T <sub>STG</sub>	-55~150	°C	
Typical Thermal Resistance					
Junction to Ambient (Note 3,4)		R <sub>θ</sub> ЈА	250	°C/W	

Limited only By Maximum Junction Temperature



### Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =-250uA	-20	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =-250uA	-0.3	-0.6	-1	
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-300mA	-	450	500	mΩ
		V <sub>GS</sub> =-2.5V, I <sub>D</sub> =-200mA	-	630	820	
		V <sub>GS</sub> =-1.8V, I <sub>D</sub> =-100mA	-	810	1200	
		V <sub>GS</sub> =-1.5V, I <sub>D</sub> =-100mA	-	1020	1600	
		V <sub>GS</sub> =-1.2V, I <sub>D</sub> =-100mA	-	1670	3000	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-20V, V <sub>GS</sub> =0V V <sub>GS</sub> = <u>+</u> 12V, V <sub>DS</sub> =0V	-	-	-1	uA
Gate-Source Leakage Current	I <sub>GSS</sub>		-	-	<u>+</u> 10	
Dynamic (Note 5)						
Total Gate Charge	Qg	V <sub>DS</sub> =-10V, I <sub>D</sub> =-200mA, V <sub>GS</sub> =-4.5V (Note 2)	-	1.1	-	nC
Gate-Source Charge	Q <sub>gs</sub>		-	0.2	-	
Gate-Drain Charge	$Q_gd$		-	0.1	-	
Input Capacitance	Ciss	V <sub>DS</sub> =-10V, V <sub>GS</sub> =0V, f=1MHZ	-	51	-	pF
Output Capacitance	Coss		-	15	-	
Reverse Transfer Capacitance	Crss		-	2.2	-	
Turn-On Delay Time	td <sub>(on)</sub>	V <sub>DD</sub> =-10V, I <sub>D</sub> =-200mA, V <sub>GS</sub> =-4.5V,	-	4.3	-	
Turn-On Rise Time	tr		-	20	-	ns
Turn-Off Delay Time	td <sub>(off)</sub>		-	33	-	
Turn-Off Fall Time	tf	R <sub>G</sub> =6Ω (Note 2)	-	25	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	Is		-	-	-300	mA
Diode Forward Voltage	$V_{\text{SD}}$	I <sub>S</sub> =-300mA, V <sub>GS</sub> =0V	-	-0.85	-1	V

#### NOTES:

- 1. Pulse width<a>300us</a>, Duty cycle<a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. R<sub>OJA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
- 4. The maximum current rating is package limited.
- 5. Guaranteed by design, not subject to production testing.



#### **TYPICAL CHARACTERISTIC CURVES**

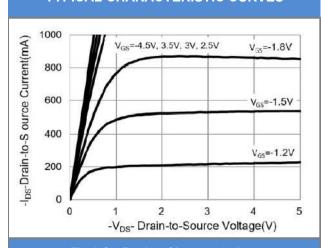
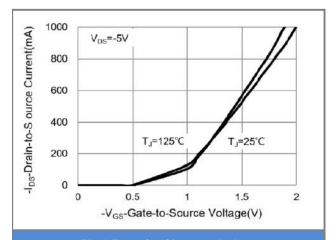


Fig.1 On-Region Characteristics



**Fig.2 Transfer Characteristics** 

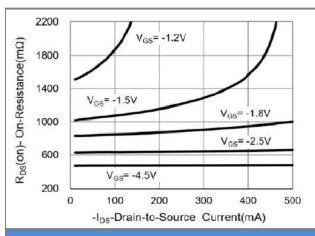


Fig.3 On-Resistance vs. Drain Current

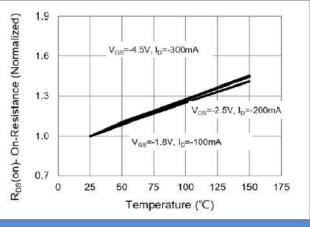


Fig.4 On-Resistance vs. Junction temperature

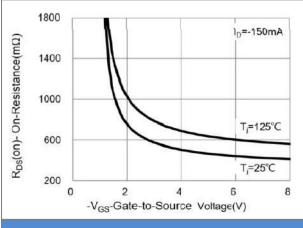
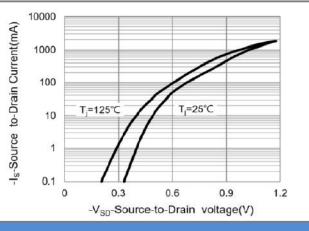


Fig.5 On-Resistance Variation with V<sub>GS</sub>



**Fig.6 Body Diode Characteristics** 



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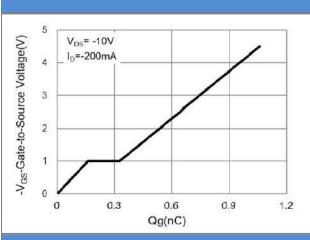


Fig.7 Gate-Charge Characteristics

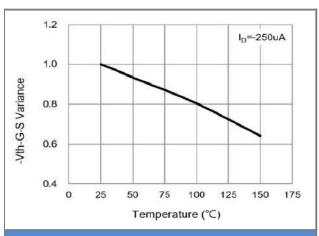


Fig.9 Threshold Voltage Variation with Temperature

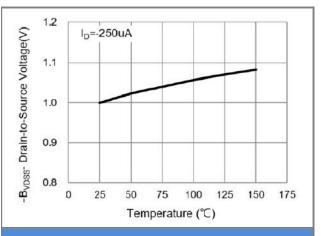


Fig.8 Breakdown Voltage Variation vs. Temperature

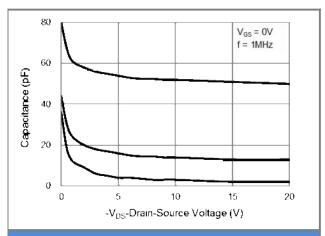


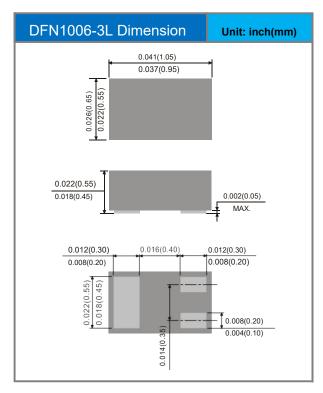
Fig.10 Capacitance vs. Drain-Source Voltage

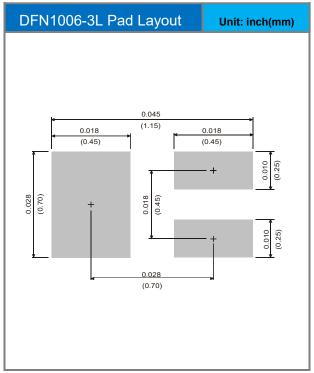


## **Part No Packing Code Version**

Part No Packing Code	Package Type	Packing Type
CSM3139DF1006-3	DFN1006-3L	10K / 7" Reel

### **Packaging Information & Mounting Pad Layout**







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